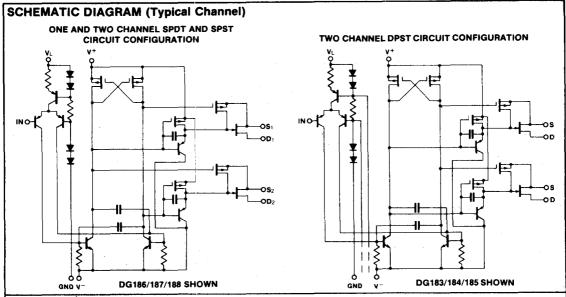
High-Speed Driver With Junction FET Switches

FEATURES

- Constant ON-resistance for signals to ±10V (DG182, 185, 188, 191), to ±7.5V (all devices)
- ±15V power supplies
- <2nA leakage from signal channel in both ON and **OFF** states
- TTL, DTL, RTL direct drive compatibility
- ton, toff <150ns, break-before-make action
- Cross-talk and open switch isolation >50dB at 10MHz (75 Ω load)

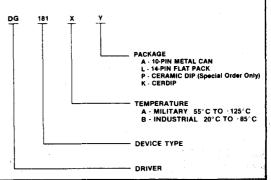
GENERAL DESCRIPTION

The DG180 thru DG191 series of analog gates consists of 2 or 4 N-channel junction-type field-effect transistors (J-FET) designed to function as electronic switches. Level-shifting drivers enable low-level inputs (0.8 to 2V) to control the ON-OFF state of each switch. The driver is designed to provide a turn-off speed which is faster than turn-on speed, so that break-before-make action is achieved when switching from one channel to another. In the ON state, each switch conducts current equally well in both directions. In the OFF condition, the switches will block voltages up to 20V peak-topeak. Switch-OFF input-output feedthrough is >50dB down at 10MHz, because of the low output impedance of the FETgate driving circuit.



ORDERING INFORMATION

ONDERING IN CHARTON			
PART NUMBER	TYPE	rDS(on) (MAX)	
DG180	Dual SPST	10	
DG181	Dual SPST	30	
DG182	Dual SPST	75	
DG183	Dual DPST	10	
DG184	Dual DPST	30	
DG185	Dual DPST	75	
DG186	SPDT	10	
DG187	SPDT	30	
DG188	SPDT	75	
DG189	Dual SPDT	10	
DG190	Dual SPDT	30	
DG191	Dual SPDT	75	



ELECTRICAL CHARACTERISTICS (CONT'D)

MAXIMUM RESISTANCES (rps(ON) MAX)

DEVICE NUMBER	MILITARY TEMPERATURE			INDUSTRIAL TEMPERATURE		UNITS	CONDITIONS (Note 1)		
	-55°C	+25°C	+125°C	-20°C	+25°C	+85°C_		$V^{+} = 15V, V^{-} = -15V, V_{L} = 5V$	
DG180	10	10	20	15	15	25	Ω	V _D = −7.5V	
DG181	30	30	60	50	50	75	Ω	$V_D = -7.5V$	
DG182	75	75	100	100	100	150	Ω	$V_D = -10V$	ļ
DG183	10	10	20	15	15	25	Ω	$V_D = -7.5V$	
DG184	30	30	60	50	50	75	Ω	$V_D = -7.5V$	
DG185	75	75	150	100	100	150	Ω	V _D = −10V	Is = -10mA
DG186	l 10	10	20	1 15	15	25	Ω	$V_D = -7.5V$	l
DG187	30	30	60	50	50	75	Ω	$V_D = -7.5V$	V _{IN} = "ON"
DG188	75	75	150	100	100	150	Ω	$V_D = -10V$	1
DG189	10	10	20	15	15	25	Ω.	$V_D = -7.5V$	ļ
DG190	30	30	60	50	50	50	Ω	$V_D = -7.5V$	
DG191	75	75	150	100	100	150	Ω	V _D = <u></u> −10V	l

APPLICATION HINT (for design only): Normally the minimum signal handling capability of the DG180 through DG191 family is 20V peak-to-peak for the 75Ω switches and 15V peak-to-peak for the 10Ω and 30Ω switches (refer I_D and I_S tests above). For other Analog Signals, the following guidelines can be used: proper switch curr-off requires that $V^- \le V_{ANALOG}(peak) - V_p$ where $V_p = 7.5V$ for the 10Ω and 30Ω switches and $V_p = 5.0V$ for 75Ω switches e.g., -10V minimum (-peak) analog signal and a 75Ω switch ($V_p = 5V$), requires that $V^- \le -10V$ -5V = -15V.

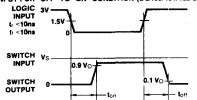


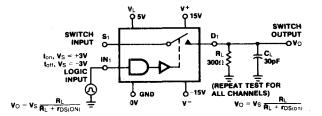
SWITCHING TIME TEST CIRCUIT

Switch output waveform shown for V_S = constant with logic input waveform as shown. Note that V_S may be + or - as per

switching time test circuit. Vo is the steady state output with switch on. Feedthrough via gate capacitance may result in spikes at leading and trailing edge of output waveform.

LOGIC INPUT FOR "OFF" TO "ON" CONDITION (DG180/181/182 SHOWN)





DUAL SPST DG180/181/182

DUAL DPST DG183/184/185

SPDT DG186/187/188 DUAL SPDT DG189/190/191

TEST CONDITIONS

DG180/181/182		
V _{IN} "ON" = 0.8V	All Channels	
V _{IN} "OFF" = 2.0V		

TEST CONDITIONS

DG183/184/185		
VIN "ON" = 2.0V	All Channels	
VIN "OFF" = 0.8V	All Channels	

TEST CONDITIONS

DG186/187/188	
VIN "ON" = 2.0V	Channel 1
VIN "ON" = 0.8V	Channel 2
VIN "OFF" = 2.0V	Channel 2
VIN "OFF" = 0.8V	Channel 1

TEST CONDITIONS

DG189/190/191		
V _{IN} "ON" = 2.0V V _{IN} "ON" = 0.8V	Channels 1 & 2	
V _{IN} "ON" = 0.8V	Channels 3 & 4	
VIN "OFF" = 2.0V	Channels 3 & 4	
VIN "OFF" = 0.8V	Channels 1 & 2	

SWITCH STATES ARE FOR LOGIC "1" INPUT = 2.0V

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